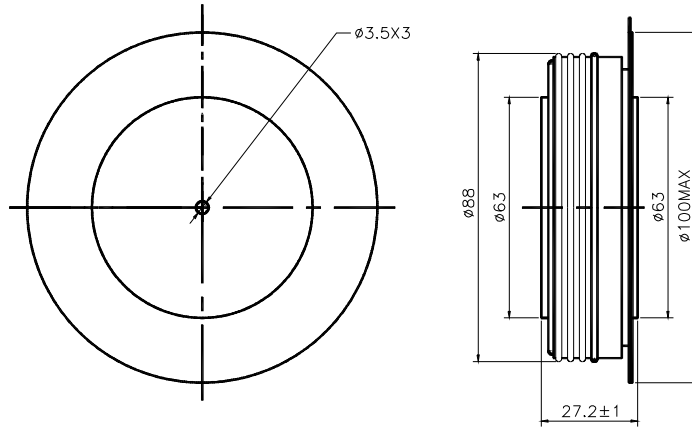


D25-XX00
RECTIFIER DIODE

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT	
				Min	Type	Max		
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Double side cooled, T _{hs} =55°C	150			3469	A	
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Double side cooled, T _{hs} =90°C	150			2572	A	
V _{RRM}	Repetitive peak reverse voltage	V _{RRM} tp=10ms V _{RSM} = V _{RRM} +100V	150	2100		3000	V	
I _{RRM}	Repetitive peak current	at V _{RRM}	150			160	mA	
I _{FSM}	Surge forward current	10ms half sine wave	150			45.1	KA	
I ² T	I ² T for fusing coordination	V _R =0.6V _{RRM}					10169	A ² s*10 ³
V _{FO}	Threshold voltage		150			0.73	V	
r _F	Forward slop resistance						0.12	mΩ
V _{FM}	Peak on-state voltage	I _{TM} =5400A, F=35KN	150			1.35	V	
I _{rm}	Reverse recovery current		150			170	A	
t _{rr}	Reverse recovery time	I _{TM} =1000A, tp=1000μs, di/dt=-40A/μs, V _R =50V					7.6	μs
Q _{rr}	Recovery charge						646	μC
R _{th(j-h)}	Thermal resistance Junction to heatsink	At 180° sine double side cooled Clamping force 35KN				0.016	°C /W	
F _m	Mounting force			30		40	KN	
T _{stg}	Stored temperature			-40		160	°C	
W _t	Weight					900	g	
Outline	ZT60cT70							

Outline



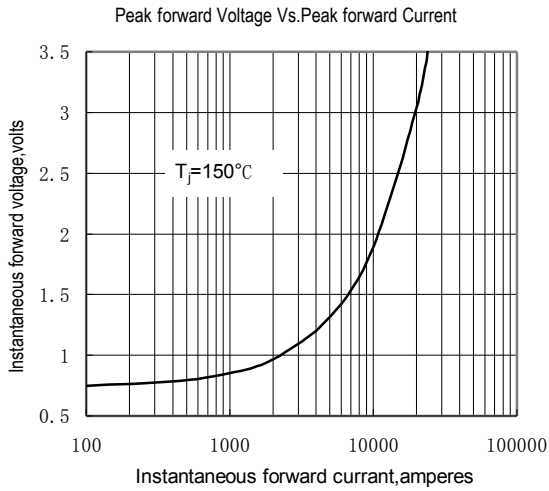


Fig.1

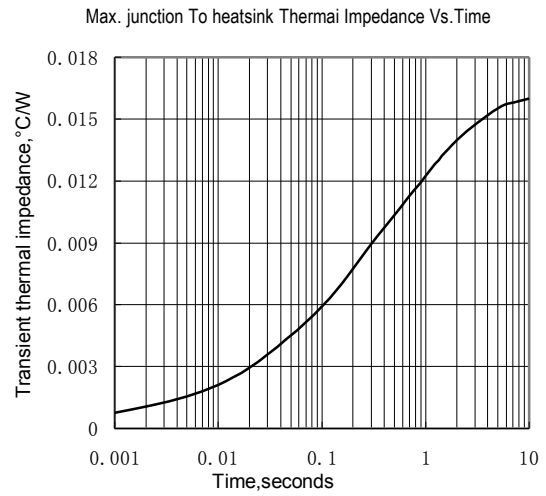


Fig.2

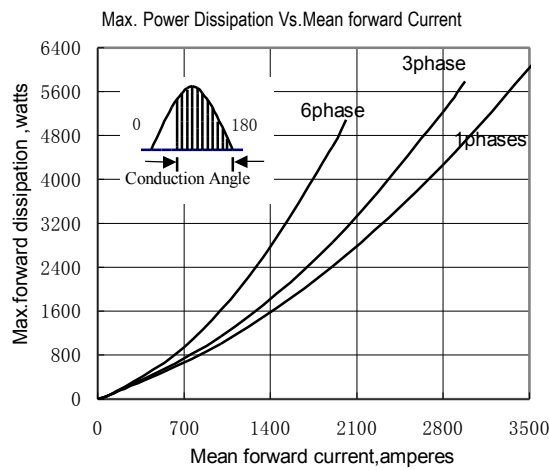


Fig.3

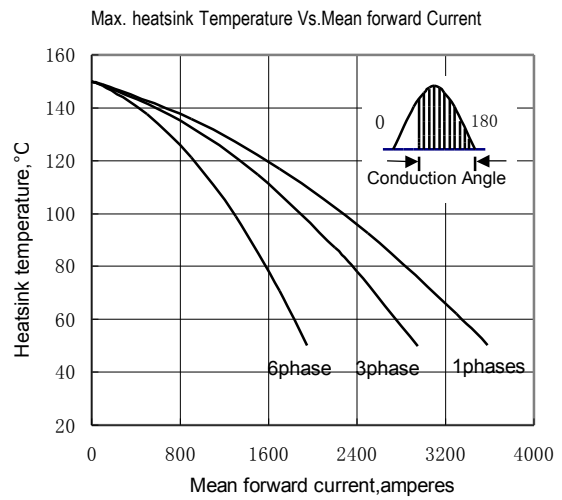


Fig.4

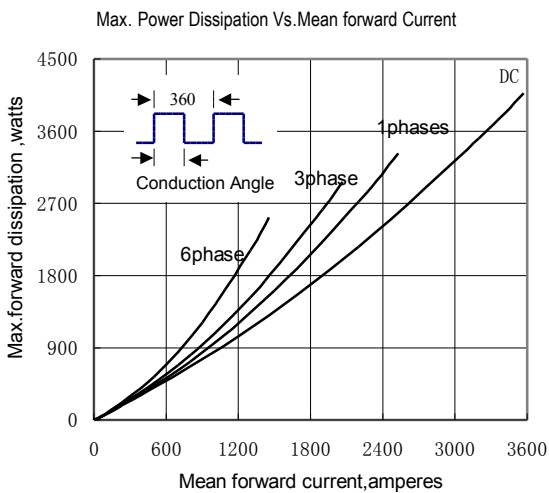


Fig.5

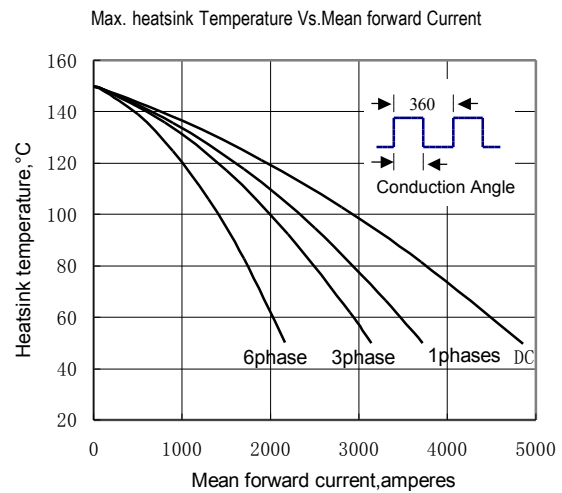


Fig.6